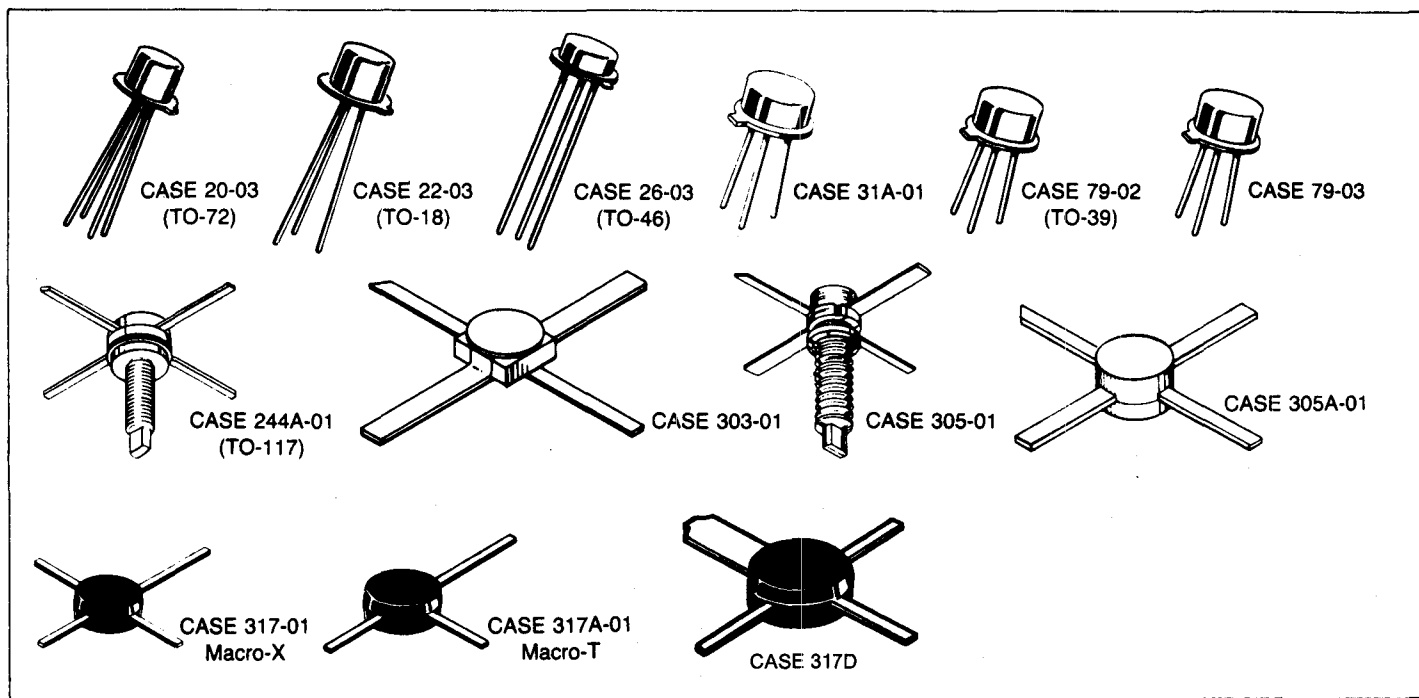


RF Small-Signal Transistors

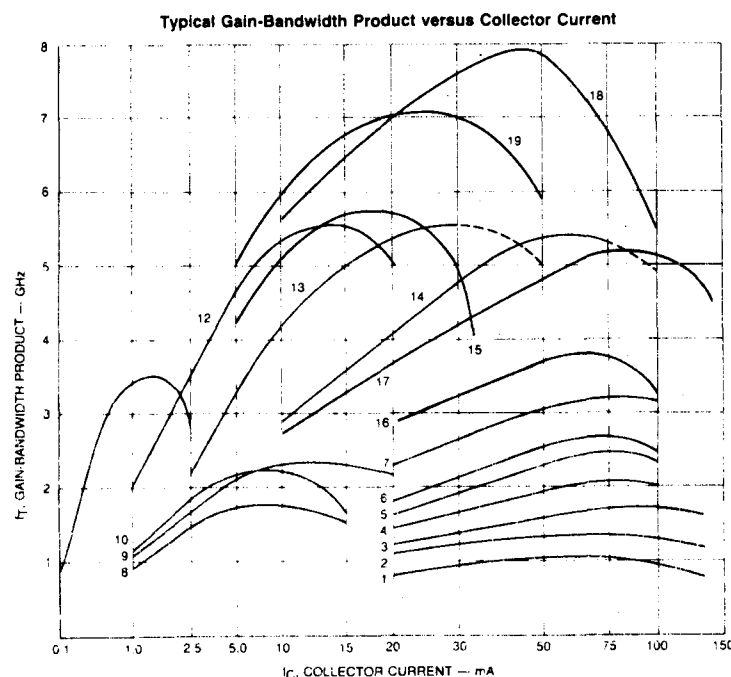
3



Motorola's small-signal, low power RF transistor product range includes transistors with gain-bandwidths of 1.0 GHz to 8.0 GHz operating at currents of 0.25 mA to over 140 mA.

These devices are available in a wide variety of package types; metal can, plastic Macro-X and Macro-T, hermetic ceramic and microminiature. Most of these transistors are fully

characterized with y or s parameters; and in addition, there are non-saturated switching characteristics, low power driver specifications, and noise figure limits. QPL types with JAN, JTX and JTXV processing levels are available as well as Hi Rel processing to meet unique customer requirements.



RF Small-Signal Transistors

Motorola small-signal and medium power RF transistors with gain-bandwidth products from 1.0 GHz to 8.0 GHz operate with currents from 0.25 mA to over 140 mA. The following chart, combined with the tables of package options, enables the circuit designer to select the optimum device from Motorola's wide range of transistor/package combinations.

- | | |
|--|-----------------------------------|
| 1 2N3866, 2N3866A | 10 2N4957, 2N4958, 2N4959, PNP |
| 2 2N5160, MM4018, PNP | 12 2N6603, BFR90, MRF901, MRF904 |
| 3 2N3948, 2N4427, MRF207 | 13 2N6604, BFR91, MRF911, MRF914 |
| 4 2N5109, 2N5943 | 14 BFR96, MRF961, MRF962, MRF965 |
| 5 2N5583, PNP | 15 BFW92A |
| 6 2N5836, 2N5837 | 16 MRF559 |
| 7 MRF511, MRF517, MRF525 | 17 MRF580, MRF581, MRF586, MRF587 |
| 8 2N2857, 2N3939, 2N5179, MRF501, MRF502 | 18 MRF571, MRF572 |
| 9 BFX89, BFY90 | 19 MRF536, MRF534, MM4049, PNP |

RF SMALL-SIGNAL TRANSISTORS (continued)

TO-72 METAL CAN

Device Type	Gain — BW		Noise Figure			Gain		Maximum Ratings		
	f _T GHz	I _C mA	NF dB	f MHz	I _C mA	dB Min	f MHz	V _{(BR)CEO} V	I _C mA	P _T mW
2N5031	1.0	5.0	2.5	450	1.0	14	450	10	20	200
2N4958*	1.0	2.0	3.3	450	2.0	16	450	30	30	200
2N4959*	1.0	2.0	3.8	450	2.0	15	450	30	30	200
2N5829*	1.2	2.0	2.5	450	2.0	17	450	30	30	200
2N4957*	1.2	2.0	3.0	450	2.0	17	450	30	30	200
MRF501	1.2	5.0	4.0	200	1.5	15**	200	15	50	200
MRF502	1.2	5.0	4.0	200	1.5	15**	200	15	50	200
BFX89	1.2	25	6.5	500	2.0	19	200	15	50	200
BFY90	1.4	25	5.0	500	2.0	21	200	15	50	200
2N5179	1.4	10	4.5	200	1.5	15	200	12	50	200
2N2857	1.6	8.0	4.1	450	1.5	12.5	450	15	40	200
MRF904	4.0	15	1.5	450	5.0	16	450	15	30	200
MRF914	4.5	20	2.0	500	5.0	15	500	12	40	200

*PNP

**Typ

HIGH VOLTAGE RF DEVICES

The devices listed below are designed for high voltage, high f_T applications similar to those in medium and high resolution colour video display monitors.

Device Type	V _{(BR)CBO} V	Gain — BW		Case Outline
		f _T GHz	I _C mA	
MRF544	120	1.4	400	TO-39
MRF545*	100	1.2	400	TO-39
MRF542	120	1.4	400	317D-01
MRF543*	100	1.2	400	317D-01

*PNP